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(Use as many sheets as necessary)			PPLICANT	First Named Inventor	Bert M. VERMEIRE		
				Art Unit	Unknown 2829		
			necessary)	Examiner Name	Unknown Arleen M. Vazquez		
Sheet	1	of	2	Attorney Docket Number	300-01-1-001		

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AV	11	A. MEKKAOUI et al., "30Mrad(SiO2) radiation tolerant pixel front end for the BTEV experiment," Nucl. Instr. and Meth. A, vol. 465, pp. 166-175, 2001.		
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AV	14	M. KIMURA, "Field and Temperature acceleration model for time-dependent dielectric breakdown," IEEE Trans. Electron Devices, vol. 46, pp. 220-229, 1999.		
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